

Data sheet acquired from Harris Semiconductor SCHS207G

February 1998 - Revised October 2003

Features

- Onboard Oscillator
- Common Reset
- Negative-Edge Clocking
- Fanout (Over Temperature Range)
- Standard Outputs 10 LSTTL Loads
- Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, II \leq 1 μA at VOL, VOH

Description

The 'HC4060 and 'HCT4060 each consist of an oscillator section and 14 ripple-carry binary counter stages. The oscillator configuration allows design of either RC or crystal oscillator circuits. A Master Reset input is provided which resets the counter to the all-0's state and disables the oscillator. A high level on the MR line accomplishes the reset function. All counter stages are master-slave flip-flops. The state of the counter is advanced one step in binary order on

CD54HC4060, CD74HC4060, CD54HCT4060, CD74HCT4060

High-Speed CMOS Logic 14-Stage Binary Counter with Oscillator

the negative transition of ϕI (and ϕO). All inputs and outputs are buffered. Schmitt trigger action on the input-pulse-line permits unlimited rise and fall times.

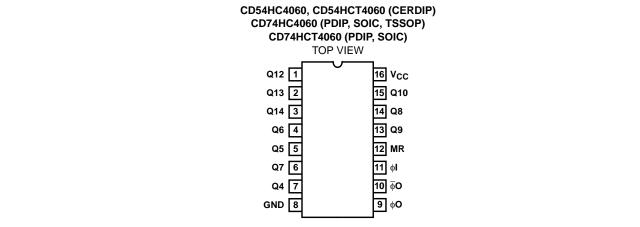
In order to achieve a symmetrical waveform in the oscillator section the HCT4060 input pulse switch points are the same as in the HC4060; only the MR input in the HCT4060 has TTL switching levels.

Ordering Information

PART NUMBER	TEMP. RANGE (^o C)	PACKAGE
CD54HC4060F3A	-55 to 125	16 Ld CERDIP
CD54HCT4060F3A	-55 to 125	16 Ld CERDIP
CD74HC4060E	-55 to 125	16 Ld PDIP
CD74HC4060M	-55 to 125	16 Ld SOIC
CD74HC4060MT	-55 to 125	16 Ld SOIC
CD74HC4060M96	-55 to 125	16 Ld SOIC
CD74HC4060PW	-55 to 125	16 Ld TSSOP
CD74HC4060PWR	-55 to 125	16 Ld TSSOP
CD74HC4060PWT	-55 to 125	16 Ld TSSOP
CD74HCT4060E	-55 to 125	16 Ld PDIP
CD74HCT4060M	-55 to 125	16 Ld SOIC
CD74HCT4060MT	-55 to 125	16 Ld SOIC
CD74HCT4060M96	-55 to 125	16 Ld SOIC

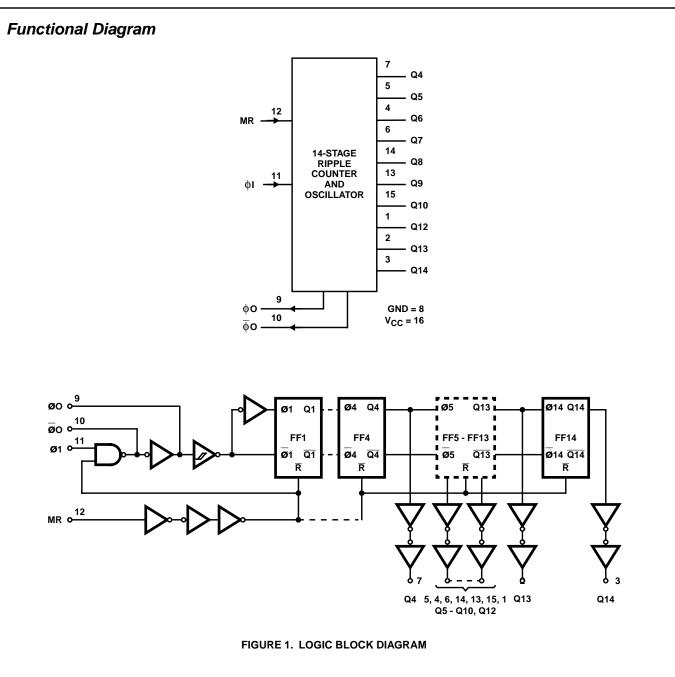
NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout



CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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øl	MR	OUTPUT STATE
↑	L	No Change
\downarrow	L	Advance to Next State
Х	Н	All Outputs are Low

Absolute Maximum Ratings

DC Supply Voltage, V _{CC}
DC Input Diode Current, I _{IK}
For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, I _{OK}
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$
DC Drain Current, per Output, IO
For $-0.5V < V_{O} < V_{CC} + 0.5V$ ±25mA
DC V _{CC} or Ground Current, I _{CC} ±50mA

Operating Conditions

Temperature Range, T_A
Supply Voltage Range, V _{CC}
HC Types
HCT Types4.5V to 5.5V
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

Thermal Information

Thermal Resistance (Typical, Note 1)	θ _{JA} (^o C/W)
E (PDIP) Package	67
M (SOIC) Package	73
PW (TSSOP) Package	108
Maximum Junction Temperature	150 ⁰ C
Maximum Storage Temperature Range6	65 ⁰ C to 150 ⁰ C
Maximum Lead Temperature (Soldering 10s)	
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TE: CONDI		v _{cc}		25 ⁰ C		-40 ⁰ C 1	O 85°C	-55 ⁰ C T	O 125 ⁰ C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES					-	_	_	-				
High Level Input	VIH	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	VIL	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V _{OH}	$V_{\text{IH}} \text{ or } V_{\text{IL}}$	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage Q Outputs CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
eme e Loude			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	7		-	-	-	-	-	-	-	-	-	V
Voltage Q Outputs TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	$V_{\text{IH}} \text{ or } V_{\text{IL}}$	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage Q Outputs CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	7		-	-	-	-	-	-	-	-	-	V
Voltage Q Outputs TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
High-Level Output	V _{OH}	V _{CC} or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage $\overline{\phi}O$ Output (Pin 10)		GND	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
CMOS Loads			-0.02	6	5.9	-	-	5.9	-	5.9	-	V

DC Electrical Specifications (Continued)

		CONDI		Vcc		25 ⁰ C		-40°C 1	O 85°C	-55°С Т	O 125 ⁰ C	
PARAMETER	SYMBOL	V ₁ (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
High-Level Output	V _{OH}	V _{CC} or	-2.6	4.5	3.98	-	-	3.84	-	3.7	-	V
Voltage		GND	-3.3	6	5.48	-	-	5.34	-	5.2	-	V
Low-Level Output	V _{OL}	V _{CC} or	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage ₀O Output (Pin 10)		GND	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
CMOS Loads			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low-Level Output	V _{OL}	V _{CC} or	2.6	4.5	-	-	0.26	-	0.33	-	0.4	V
Voltage ∳O Output (Pin 10) TTL Loads		GND	3.3	6	-	-	0.26	-	0.33	-	0.4	V
High-Level Output	VOH	V _{IL} or V _{IH}	-3.2	4.5	3.98	-	-	3.84	-	3.7	-	V
Voltage			-4.2	6	5.48	-	-	5.34	-	5.2	-	V
Low-Level Output	V _{OL}	V _{IL} or V _{IH}	-2.6	4.5	-	-	0.26	-	0.33	-	0.4	V
Voltage			-3.3	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μA
HCT TYPES												
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	VIL	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage Q Outputs CMOS Loads	VOH	V _{IH} or V _{IL} (Note 3)	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage Q Outputs TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage Q Outputs CMOS Loads	V _{OL}	V _{IH} or V _{IL} (Note 3)	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage Q Outputs TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
High-Level Output Voltage ∳O Output (Pin 10) CMOS Loads	V _{OH}	V _{CC} or GND	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High-Level Output Voltage ∳O Output (Pin 10) TTL Loads (Note 2)	V _{OH}	V _{CC} or GND	-2.6	4.5	3.98	-	-	3.84	-	3.7	-	V
Low-Level Output Voltage ∳O Output (Pin 10) CMOS Loads	V _{OL}	V _{CC} or GND	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V

		TES CONDI		V _{CC}		25 ⁰ C		-40°C T	O 85°C	-55°C T	O 125ºC	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Low-Level Output Voltage ∳O Output (Pin 10) TTL Loads	V _{OL}	V _{CC} or GND	2.6	4.5	-	-	0.26	-	0.33	-	0.4	V
High-Level Output Voltage	V _{OH}	V _{IL} or V _{IH}	-3.2	4.5	3.98	-	-	3.84	-	3.7	-	V
Low-Level Output Voltage	V _{OL}	V _{IH} or V _{IL} (Note 3)	3.2	4.5	-		0.26	-	0.33	-	0.4	V
Input Leakage Current	Ιį	Any Voltage Between V _{CC} and GND	-	5.5	-		±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	∆I _{CC} (Note 4)	V _{CC} - 2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μA

DC Electrical Specifications (Continued)

NOTES:

2. Limits not valid when pin 12 (instead of pin 11) is used as control input.

3. For pin 11 V_{IH} = 3.15V, V_{IL} = 0.9V.

4. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
MR	0.35

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications Table, e.g. $360\mu A$ max at $25^{\circ}C$.

Prerequisite for Switching Specifications

						25°C		-40	°C TO 8	5°C	-55 ⁰	°C TO 12	5°C	
PARAMETER	SYMBOL	V _{CC} (V)	MIN	TYP	MAX	MIN	TYP	MAX	MIN	ТҮР	MAX	UNITS		
HC TYPES														
Maximum Input Pulse	f _{max}	2	6	-	-	5	-	-	4	-	-	MHz		
Frequency		4.5	30	-	-	25	-	-	20	-	-	MHz		
		6	35	-	-	29	-	-	23	-	-	MHz		
Input Pulse Width	t _W	2	80	-	-	100	-	-	120	-	-	ns		
		4.5	16	-	-	20	-	-	24	-	-	ns		
		6	14	-	-	17	-	-	20	-	-	ns		
Reset Removal Time	t _{REM}	2	100	-	-	125	-	-	150	-	-	ns		
		4.5	20	-	-	25	-	-	30	-	-	ns		
		6	17	-	-	21	-	-	26	-	-	ns		

CD54/74HC4060, CD54/74HCT4060

Prerequisite for Switching Specifications (Continued)

			25 ^o C			-40 ⁰ C TO 85 ⁰ C			-55°C TO 125°C			
PARAMETER	SYMBOL	V _{CC} (V)	MIN	ТҮР	MAX	MIN	ТҮР	MAX	MIN	ТҮР	MAX	UNITS
Reset Pulse Width	t _W	2	80	-	-	100	-	-	120	-	-	ns
		4.5	16	-	-	20	-	-	24	-	-	ns
		6	14	-	-	17	-	-	20	-	-	ns
HCT TYPES	•				•					•		
Maximum Input, Pulse Frequency	f _{max}	4.5	30	-	-	25	-	-	20	-	-	MHz
Input Pulse Width	t _W	4.5	16	-	-	20	-	-	24	-	-	ns
Reset Removal Time	t _{REM}	4.5	26	-	-	33	-	-	39	-	-	ns
Reset Pulse Width	t _W	4.5	25	-	-	31	-	-	38	-	-	ns

Switching Specifications Input $t_{\text{f}},\,t_{\text{f}}=6\text{ns}$

		TEST			25 ⁰ C			с то ⁰С		C TO 5°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	
HC TYPES					-						
Propagation Delay	tPLH, tPHL	C _L = 50pF	2	-	-	300	-	375	-	450	ns
φI to Q4			4.5	-	-	60	-	75	-	90	ns
		C _L = 15pF	5	-	25	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	51	-	64	-	78	ns
Q _n to Q _{n+1}	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	80	-	100	-	120	ns
			4.5	-	-	16	-	20	-	24	ns
		C _L = 15pF	5	-	6	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	14	-	17	-	20	ns
MR to Q _n	t _{PHL}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
			4.5	-	-	35	-	44	-	53	ns
		C _L = 15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns
Output Transition Time	t _{THL} , t _{TLH}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C _I (TBD)										
Propagation Dissipation Capacitance (Notes 5, 6)	C _{PD}	-	-	-	40	-	-	-	-	-	pF
HCT TYPES											
Propagation Delay	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	-	-	-	-	-	-ns
φl to Q4			4.5	-	-	66	-	83	-	100	ns
		C _L = 15pF	5	-	25	-	-	-	-	-	-ns
		C _L = 50pF	6	-	-	-	-	-	-	-	-ns

		TEST		25 ⁰ C			-40 ^о С ТО 85 ^о С		-55 ⁰ C TO 125 ⁰ C		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
Q _n to Q _{n+1}	t _{PLH} , t _{PHL}	$C_L = 50 pF$	2	-	-	-	-	-	-	-	ns
			4.5	-	-	16	-	20	-	24	ns
		C _L = 15pF	5	-	6	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	-	-	-	-	-	ns
MR to Q _n	t _{PHL}	C _L = 50pF	2	-	-	-	-	-	-	-	ns
			4.5	-	-	44	-	55	-	66	ns
		C _L = 15pF	5	-	17	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	-	-	-	-	-	ns
Output Transition Time	t _{THL} , t _{TLH}	C _L = 50pF	2	-	-	-	-	-	-	-	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	-	-	-	-	-	ns
Input Capacitance	C _I (TBD)										
Propagation Dissipation Capacitance (Notes 5, 6)	C _{PD}	-	-	-	40	-	-	-	-	-	pF

Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

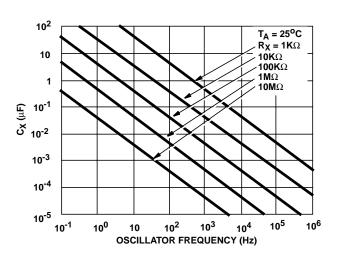
NOTES:

5. $C_{\mbox{PD}}$ is used to determine the dynamic power consumption, per package.

6. $P_D = C_{PD} V_{CC}^2 f_i \Sigma (C_L V_{CC}^2 f_i/M)$ where $M = 2^1, 2^2, 2^3, ...2^{14}, f_i = input$ frequency, $C_L = output$ load capacitance.

PARAMETER	TEST CONDITIONS	VOLTAGE	TYPICAL MAXIMUM LIMITS
R _X Minimum	C _X > 1000pF	2	1KΩ
	C _X > 10pF	4.5	
	C _X > 10pF	6	
R _X Maximum	C _X > 10pF	2	20MΩ
	C _X > 10pF	4.5	
	C _X > 10pF	6	
C _X Minimum	R _X > 10KΩ	2	10pF
	R _X > 10KΩ	4.5	
	R _X > 10KΩ	6	
	R _X = 1KΩ	2	1000pF
	R _X = 1KΩ	4.5	10pF
	R _X = 1KΩ	6	10pF
Maximum Astable Oscillator	C _X = 1000pF, R _X = 1KΩ	2	0.5MHz (Note 7)
Frequency	$C_X = 100 pF,$ $R_X = 1 K\Omega$	4.5	3MHz (Note 7)
	$C_X = 100 pF,$ $R_X = 1 K \Omega$	6	3MHz (Note 7)

TYPICAL LIMIT VALUES FOR R_X AND C_X

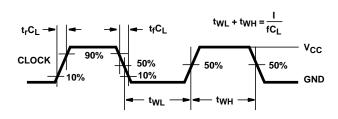


NOTE: OSC Frequency $\approx 1/2.2 R_X C_X$ For $1M\Omega > R_X > 1K\Omega$, $C_X > 10pF$, f < 1MHz FIGURE 2. FREQUENCY OF ON-BOARD OSCILLATOR AS A FUNCTION OF C_X AND R_X

NOTE:

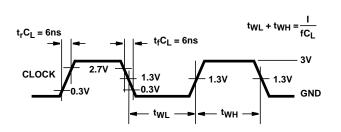
7. At very high frequencies f = $1/2.2 R_X C_X$ no longer gives an accurate approximation.

Typical Performance Curves



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%. FIGURE 3. HC CLOCK PULSE RISE AND FALL TIMES AND

PULSE WIDTH



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%. FIGURE 4. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

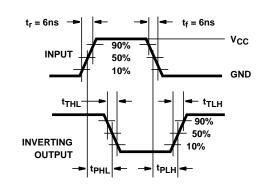


FIGURE 5. HC AND HCT TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC

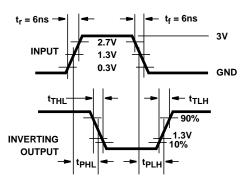


FIGURE 6. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC



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PACKAGING INFORMATION

Orderable Device	Status	Package Type	-	Pins		Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
5962-8768001EA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8768001EA CD54HC4060F3A	Samples
5962-8977101EA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8977101EA CD54HCT4060F3A	Samples
CD54HC4060F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8768001EA CD54HC4060F3A	Samples
CD54HCT4060F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8977101EA CD54HCT4060F3A	Samples
CD74HC4060E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4060E	Samples
CD74HC4060M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4060M	Samples
CD74HC4060M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4060M	Samples
CD74HC4060M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4060M	Samples
CD74HC4060M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4060M	Samples
CD74HC4060MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4060M	Samples
CD74HC4060MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4060M	Samples
CD74HC4060PW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4060	Samples
CD74HC4060PWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4060	Samples
CD74HC4060PWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4060	Samples
CD74HC4060PWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4060	Samples
CD74HC4060PWT	ACTIVE	TSSOP	PW	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4060	Samples
CD74HCT4060E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT4060E	Samples



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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HCT4060EE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT4060E	Samples
CD74HCT4060M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4060M	Samples
CD74HCT4060M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4060M	Samples
CD74HCT4060M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4060M	Samples
CD74HCT4060MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4060M	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



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10-Jun-2014

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OTHER QUALIFIED VERSIONS OF CD54HC4060, CD54HCT4060, CD74HC4060, CD74HCT4060 :

- Catalog: CD74HC4060, CD74HCT4060
- Military: CD54HC4060, CD54HCT4060

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

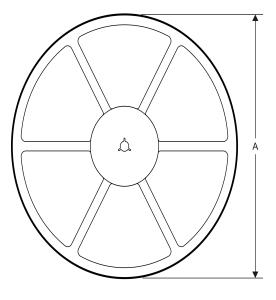
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

Texas Instruments





TAPE AND REEL INFORMATION

*All dimensions are nominal

TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4060M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4060PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HC4060PWT	TSSOP	PW	16	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HCT4060M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

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PACKAGE MATERIALS INFORMATION

14-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC4060M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HC4060PWR	TSSOP	PW	16	2000	367.0	367.0	35.0
CD74HC4060PWT	TSSOP	PW	16	250	367.0	367.0	35.0
CD74HCT4060M96	SOIC	D	16	2500	333.2	345.9	28.6

J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. β . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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